# MSR601-ST1

Preferred Device

# NPN General Purpose Amplifier Transistors Surface Mount

### Features

• Pb–Free Packages are Available



Rating	Symbol	Value	Unit
Collector – Base Voltage	V <sub>(BR)CBO</sub>	60	Vdc
Collector – Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc
Emitter – Base Voltage	V <sub>(BR)EBO</sub>	7.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc
Collector Current – Peak	I <sub>C(P)</sub>	200	mAdc

THERMAL CHARACTERISTICS

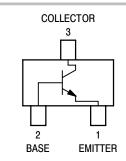
Characteristic	Symbol	Max	Unit
Power Dissipation	PD	200	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 ~ +150	°C

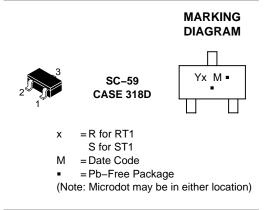
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

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## MSD601-RT1, MSD601-ST1

## E FOTRICAG (TA = 25°C)

Characteristic	Symbol	Min	Max	Unit
Collector – Emitter Breakdown Voltage $(I_C = 2.0 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	50	_	Vdc
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	V <sub>(BR)CBO</sub>	60	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	70	-	Vdc
Collector – Base Cutoff Current ( $V_{CB} = 45$ Vdc, $I_E = 0$ )	I <sub>CBO</sub>	-	0.1	μAdc
Collector – Emitter Cutoff Current ( $V_{CE} = 10 \text{ Vdc}, I_B = 0$ )	I <sub>CEO</sub>	-	100	nAdc
DC Current Gain (Note 1) ( $V_{CE} = 10$ Vdc, $I_C = 2.0$ mAdc) MSD601-RT1 MSD601-ST1 ( $V_{CE} = 2.0$ Vdc, $I_C = 100$ mAdc)	h <sub>FE1</sub> h <sub>FE2</sub>	210 290 90	340 460 -	-
Collector – Emitter Saturation Voltage ( $I_C = 100 \text{ mAdc}, I_B = 10 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	-	0.5	Vdc

1. Pulse Test: Pulse Width  $\leq$  300 µs, D.C.  $\leq$  2%.

### **ORDERING INFORMATION**

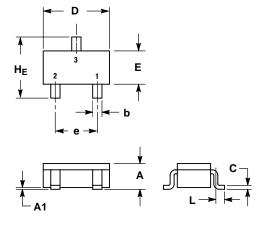
Device	Package	Shipping <sup>†</sup>	
MSD-601RT1	SC-59	3000 Units / Reel	
MSD-601RT1G	SC-59 (Pb-Free)	3000 Units / Reel	
MSD-601ST1	SC-59	3000 Units / Reel	
MSD-601ST1G	SC–59 (Pb–Free)	3000 Units / Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## 查询"MSD601-RT1-D"供应商

PACKAGE DIMENSIONS

SC-59 CASE 318D-04 ISSUE G

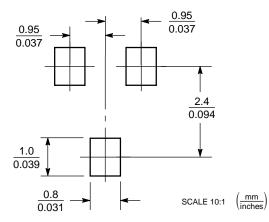


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
q	0.35	0.43	0.50	0.014	0.017	0.020
С	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
Ш	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

查询"MSD601-RT1-D"供应商

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